
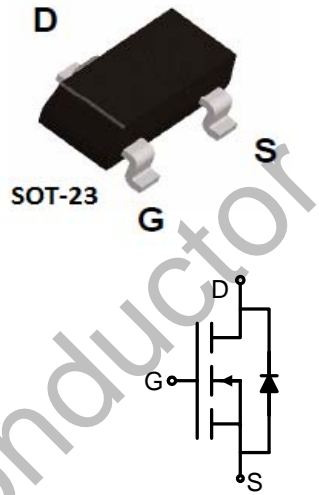


**WG2306**  
30V N-Channel MOSFET

**Features:**

- Low Intrinsic Capacitances.
- Excellent Switching Characteristics.
- Extended Safe Operating Area.
- Unrivalled Gate Charge :Qg= 5.2nC (Typ.).
- BVDS=30V, ID=5.0A
- RDS(on) : 31 mΩ (Max) @VG=10V
- 100% Avalanche Tested

SOT-23 



MARKING: A6XT      Schematic diagram

**Absolute Maximum Ratings (TA=25°C unless otherwise noted)**

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	5.0	A
Drain Current-Pulsed <sup>(Note 1)</sup>	I <sub>DM</sub>	20	A
Maximum Power Dissipation	P <sub>D</sub>	1.4	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 To 150	°C

**Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient <sup>(Note 2)</sup>	R <sub>θJA</sub>	89	°C/W
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**Electrical Characteristics ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	30	33	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=30V, V_{GS}=0V$	-	-	1	$\mu A$

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>On Characteristics (Note 3)</b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.2	1.6	2.4	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=5A$	-	25.5	31	$m\Omega$
		$V_{GS}=4.5V, I_D=4A$	-	36	43	$m\Omega$
Forward Transconductance	$g_{FS}$	$V_{DS}=5V, I_D=5A$	-	15	-	S
<b>Dynamic Characteristics (Note 4)</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=15V, V_{GS}=0V,$ $F=1.0MHz$	-	485.8	-	PF
Output Capacitance	$C_{oss}$		-	65.2	-	PF
Reverse Transfer Capacitance	$C_{rss}$		-	54	-	PF
<b>Switching Characteristics (Note 4)</b>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=15V, R_L=3\Omega$ $V_{GS}=10V, R_{GEN}=3\Omega$	-	5	-	nS
Turn-on Rise Time	$t_r$		-	3	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	15	-	nS
Turn-Off Fall Time	$t_f$		-	3.5	-	nS
Total Gate Charge	$Q_g$	$V_{DS}=15V, I_D=6A,$ $V_{GS}=10V$	-	12.6	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.9	-	nC
Gate-Drain Charge	$Q_{gd}$		-	2.6	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	$V_{SD}$	$V_{GS}=0V, I_S=6A$	-	-	1.2	V
Diode Forward Current (Note 2)	$I_S$		-	-	5.8	A

**Notes:**

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production

Typical Characteristics

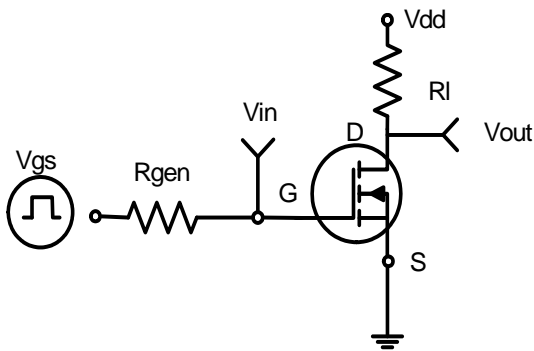


Figure 1: Switching Test Circuit

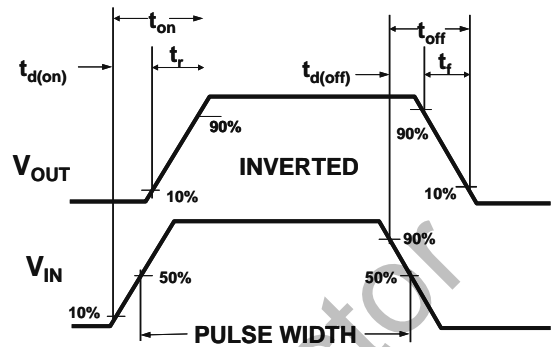


Figure 2: Switching Waveforms

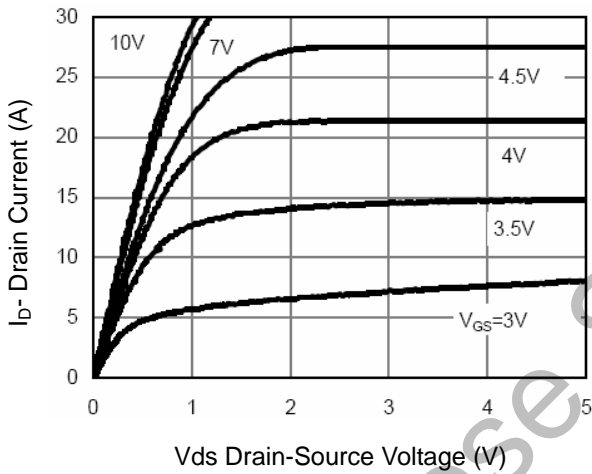


Figure 3 Output Characteristics

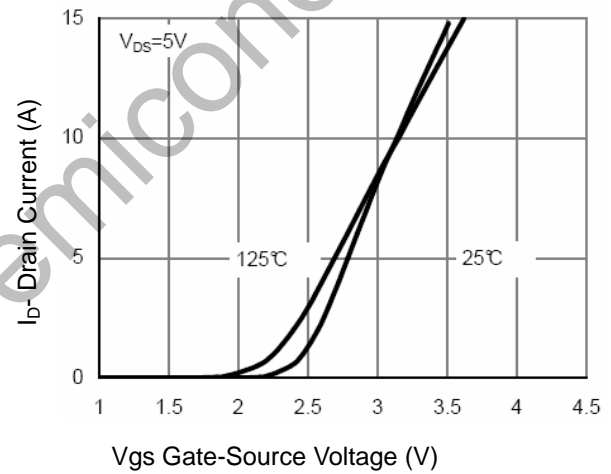


Figure 4 Transfer Characteristics

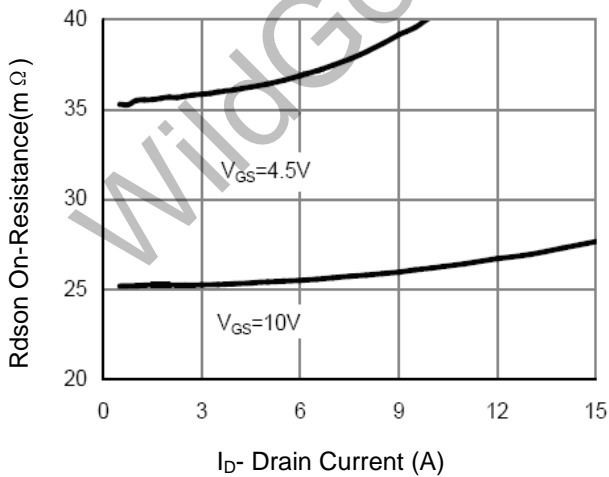


Figure 5 Drain-Source On-Resistance

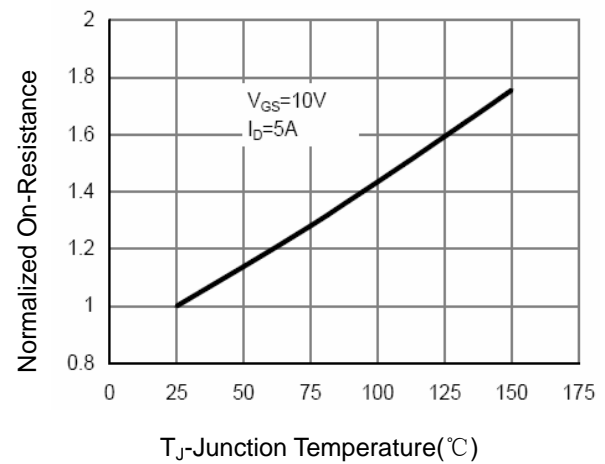
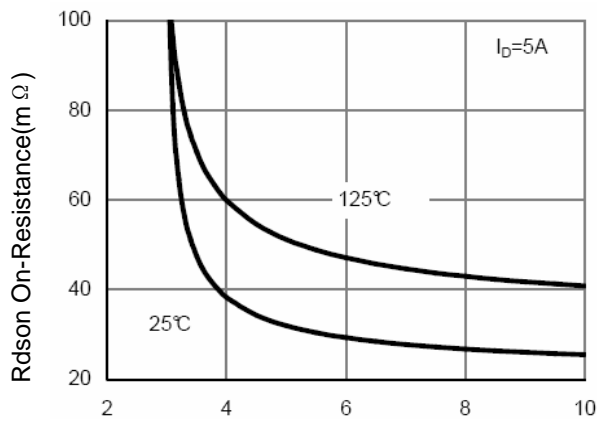
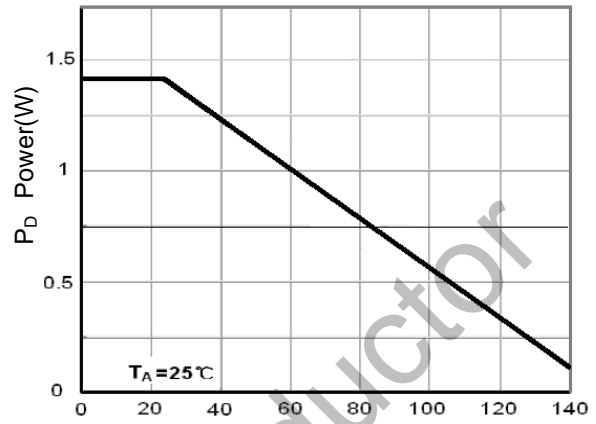


Figure 6 Drain-Source On-Resistance

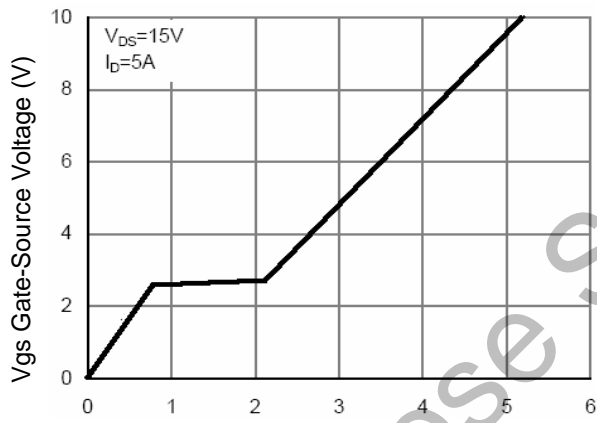
Typical Characteristics (Continued)



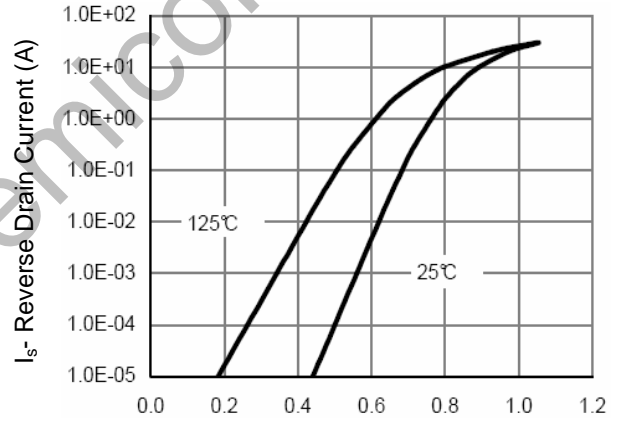
Vgs Gate-Source Voltage (V)  
Figure 7 Rdson vs Vgs



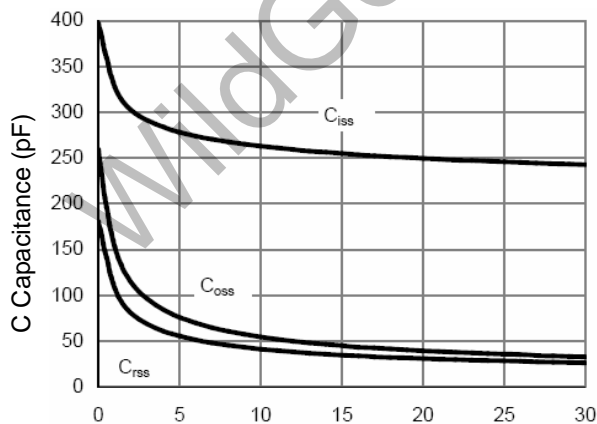
Tj-Junction Temperature (°C)  
Figure 8 Power Dissipation



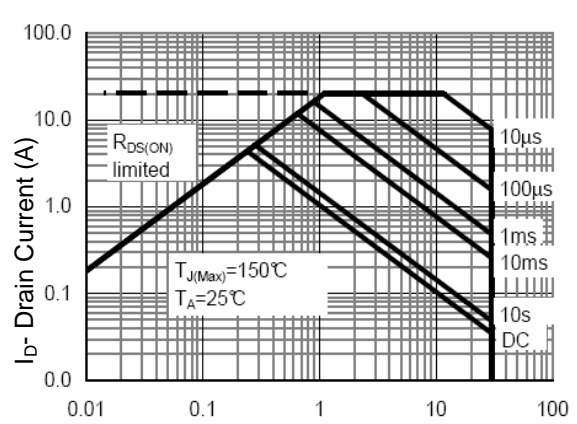
Qg Gate Charge (nC)  
Figure 9 Gate Charge



Vds Drain-Source Voltage (V)  
Figure 10 Source-Drain Diode Forward



Vds Drain-Source Voltage (V)  
Figure 11 Capacitance vs Vds



Vds Drain-Source Voltage (V)  
Figure 12 Safe Operation Area

Typical Characteristics (Continued)

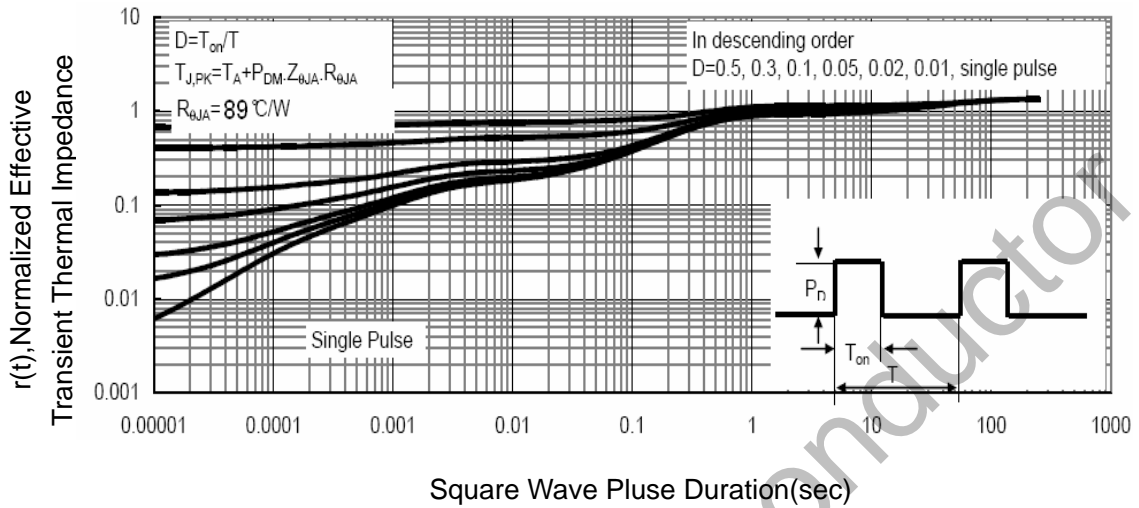


Figure 13 Normalized Maximum Transient Thermal Impedance

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